

Symmetry and temperature dependence of the order parameter in MgB₂ from point contact measurements

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(Received 26 March 2001; published 24 July 2001)

We have performed differential conductance versus voltage measurements of Au/MgB₂ point contacts. We find that the dominant component in the conductance is due to Andreev reflection. The results are fitted to the theoretical model of BTK for an *s*-wave symmetry from which we extract the value of the order parameter (Δ) and its temperature dependence. From our results we also obtain a lower experimental bound on the Fermi velocity in MgB₂.

DOI: 10.1103/PhysRevB.64.060506

PACS number(s): 74.70.Ad, 74.80.Fp

Recently superconductivity was discovered in magnesium diboride by Nagamatsu *et al.*¹ with a critical temperature T_c of 39 K. The discovery was followed by weak link measurements in the tunneling regime. Rubio-Bollinger *et al.*² used a scanning tunneling microscope (STM) to measure tunneling into small grains of MgB₂ embedded in a gold matrix. The measurement was done at a temperature of 2.5 K. A good fit was found to the BCS model with a *s*-wave symmetry gap ($\Delta = 2$ meV). Sharoni *et al.*³ used STM to measure a bulk sample of MgB₂ at $T = 4.2$ K. They also found a good fit to a BCS model with an isotropic order parameter of a larger amplitude ($\Delta = 5 - 7$ meV). We report here on the temperature dependence of point contact measurements on MgB₂ in the Sharvin limit.⁴ From these measurements we extract the temperature dependence of the order parameter and calculate a lower bound for the Fermi velocity in MgB₂. The resulting spectra can be fitted according to the BTK (Ref. 5) formalism with an *s*-wave symmetry order parameter, with amplitudes in the range of 3–4 meV at $T \ll T_c$. The barrier parameter $Z = H/\hbar v_F$ (where H is the height of the potential between the normal metal and the superconductor) values obtained were between 0.57 to 0.9, indicating a dominant Andreev reflection⁶ component in the conductance. Andreev reflection is a unique property of a superconducting material, in which a phase coherent state consisting of Cooper pairs is formed below T_c . This reflection occurs at the interface between a normal metal and a superconductor. An electron approaching the superconductor from the normal metal with energy smaller than the energy gap of the superconductor cannot enter as a quasiparticle into the superconducting condensate. Instead the electron is reflected as a hole and a Cooper pair is added to the condensate. This process results in an increase of the conductivity of the contact for voltages smaller than Δ/e (where e is the electron charge). This is different from the case of a tunnel junction, in which one measures a decrease in the conductance below Δ , resulting from a decrease in the density of states of quasiparticles in the superconductor.

The MgB₂ sample that we measured is of the same source as that used in Ref. 3 and was prepared following the procedure reported in Ref. 7. The superconducting transition found by a magnetization measurement gave $T_c = 39$ K.³ Details on sample preparation and characterization can be found in Ref.

3. The point contacts were obtained using an Au tip mounted on a differential screw. Details on the technique can be found in Achsaf *et al.*⁸ Prior to the measurement the sample was polished with a silicone carbide paper (2500 grit). I (V) characteristics of the contacts were measured digitally and differentiated numerically using a computer program. Each measurement comprises of two successive cycles in order to check for the absence of heating hysteresis effects. The conductance curves are symmetrical with respect to voltage. All figures show the spectra after normalization, the conductance data being divided by the value of the conductance at $V > \Delta$, where it reaches a constant value.

In Fig. 1 we show the differential conductance of the highest resistance contact R ($V = 25$ mV) = 45 Ω at a temperature of 4.2 K. The data was fitted using an *s*-wave symmetry order parameter with $\Delta = 4$ meV, $Z = 0.9$, and a smearing factor $\Gamma = 2$ meV. Figure 2 shows the data for a contact with a resistance of R ($V = 25$ mV) = 24 Ω at a temperature of 4.2 K. Fitting parameters are $\Delta = 3.8$ meV, $Z = 0.75$, and $\Gamma = 1.5$ meV.

In Fig. 3(a) we show the characteristics of our lowest Z contact, measured at 7.4 K. The contact resistance was R ($V = 25$ mV) = 9 Ω . The data was fitted with *s*-wave symmetry $\Delta = 3$ meV, $Z = 0.57$, and $\Gamma = 0.75$ meV. As explained in Ref. 5, the barrier parameter, Z , obtained from the fit to the experimental curves, results both from inelastic scattering in the contact and from the mismatch of Fermi velocities between the two electrodes. In addition Ref. 5 gives a formula which takes into account both of these effects, $Z_{\text{eff}} = [Z^2 + (1 - r)^2/4r]^{1/2}$, where Z represents the barrier scattering and r

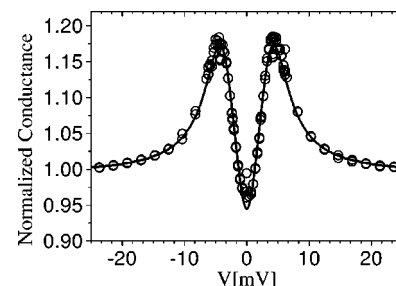


FIG. 1. Normalized conductance versus voltage of Au/MgB₂ contact measured at 4.2 K. R ($V = 25$ mV) = 45 Ω (circles). BTK fit: $\Delta = 4$ meV, $Z = 0.9$, $T = 4.2$ K, and $\Gamma = 2.0$ meV (line).

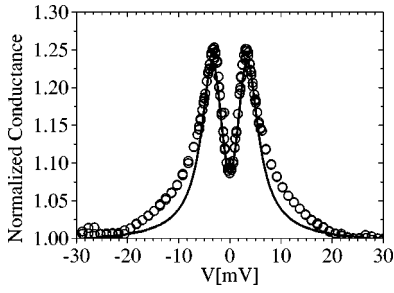


FIG. 2. Normalized conductance versus voltage of Au/MgB₂ contact measured at 4.2 K. $R(V=25\text{ mV})=25\ \Omega$ (circles). BTK fit: $\Delta=3.8\text{ meV}$, $Z=0.75$, $T=4.2\text{ K}$, and $\Gamma=1.5\text{ meV}$ (line).

is the ratio of the Fermi velocities. The value obtained from the fit to the experimental data is Z_{eff} . Using our lowest obtained Z_{eff} value of 0.57 we find that $r < 3$, which gives for the Fermi velocity of MgB₂ a lower bound of $4.7 \times 10^7\text{ cm/sec}$ [where we have used $1.4 \times 10^8\text{ cm/sec}$ as the

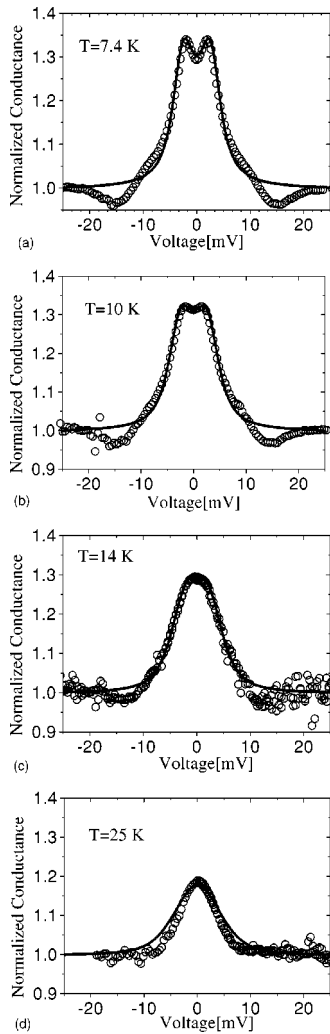


FIG. 3. Normalized conductance versus voltage of Au/MgB₂ contact measured as a function of temperature. $R(V=25\text{ mV})=9\ \Omega$ (circles). BTK fit: $Z=0.57$ and $\Gamma=0.75\text{ meV}$ (line). (a) $T=7.4\text{ K}$, $\Delta=3\text{ meV}$; (b) $T=10\text{ K}$, $\Delta=3\text{ meV}$; (c) $T=14\text{ K}$, $\Delta=2.7\text{ meV}$; (d) $T=25\text{ K}$, $\Delta=1.8\text{ meV}$.

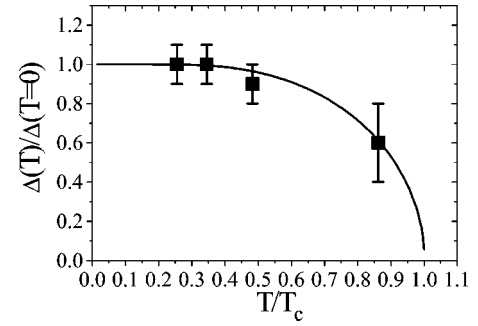


FIG. 4. Amplitude of the order parameter (Δ) as a function of temperature. Data of the contact presented in Fig. 3 (squares). BCS fit with $\Delta(T=0)=3\text{ meV}$ and $T_c=29\text{ K}$ (line).

Fermi velocity of Au (Ref. 9)]. This is in agreement with the value of the average Fermi velocity of $4.8 \times 10^7\text{ cm/sec}$ calculated by Kurtus *et al.*¹⁰ At voltages above 6 mV the BTK theory fails however to explain the data. First the measured conductance rises above the BTK fit until it reaches a maximum separation around 8.6 mV, then it crosses the fit line and continues below it until a maximum separation at around 15 mV. The data and the fit join around 20 mV. This behavior is seen both for negative and for positive bias. As this phenomenon is not observed in the other contacts (Fig. 1 and Fig. 2), we cannot be sure whether it is related to intrinsic properties of the material, as for example due to the bosons mediating the attractive el-el interaction, or if it is due to a local effect specific for this contact. We subsequently measured the same contact at different temperatures: 10, 14, and 25 K. This is shown in Figs. 3(b), 3(c), and 3(d). We find that the resistance at high voltage is constant at the different temperatures. We used the same Z and the same Γ , as for the 7.4 K measurement and changed only Δ and T , to fit the data. From this procedure we were able to extract Δ as a function of temperature in Fig. 4. We were able to fit the data to the BCS prediction using $\Delta(0)=3\text{ meV}$ and $T_c=29\text{ K}$. This T_c is lower than the bulk critical temperature of 39 K. However, if we assume that the highest gap value we measured of 4 meV corresponds to the bulk T_c and that Δ is proportional to a local T_c we get $T_c(\Delta=3\text{ meV})=(3/4) \times 39=29.3\text{ K}$. This is then in agreement with our fitted value. In any case, the value of T_c predicted by the weak coupling limit, $\Delta(0)/k_B T_c=1.76$, for $\Delta(0)=3\text{ meV}$ is 19.8 K, while our data show that T_c of the contact is definitely above 25 K. This gives an upper limit to the ratio $\Delta(0)/k_B T_c$ of 1.4, lower than the BCS weak coupling value of 1.75. We obtain for $\Delta(0)/k_B T_c$ the same value of 1.4 if we use our highest measured value of $\Delta=4\text{ meV}$ and $T_c=39\text{ K}$. Using the BCS expression $\xi_0=\hbar v_F/\pi\Delta$, and our lower bound for $v_F=4.7 \times 10^7\text{ cm/sec}$, gives $\xi_0 \cong 250\ \text{\AA}$. This value is smaller than the mean free path value of 600 \AA given by Ref. 11; thus we find that MgB₂ is intrinsically in the clean limit, since the value of ξ_0 that we calculated is independent of the mean free path. The value of the mean free path is also larger than the size of the point contact $a \cong 20\text{ to }40\ \text{\AA}$, which we calculate from the measured contact resistance and the fitted Z value. [Using the relations $R_n=R_0(1+Z^2)$ and $R_0=\rho/4a^2$ (Ref. 5) and the value for ρ from Ref. 11]. Our contacts are

thus in the Sharvin limit ($a \ll l$).

In conclusion we showed data of low Z , point contact measurements on MgB_2 . The data was fitted using the BTK model for an s -wave symmetry order parameter. The data has a dominant component of Andreev reflection, which is a sign of a phase coherent state formed by the electrons. From the Z value of the fit, we calculated a lower bound of 4.7×10^7 cm/sec for the Fermi velocity MgB_2 . The temperature dependence of the order parameter amplitude is consistent

with the BCS prediction. However, an upper limit on the ratio $2\Delta(0)/k_B T$ of 2.8 is found which is smaller than the BCS weak limit prediction.

We would like to thank I. Felner for supplying the MgB_2 sample and I. Felner, O. Millo, and A. Sharoni for useful discussions. This work was supported in part by the Heinrich Hertz-Minerva Center for High Temperature Superconductivity, by a grant from DARPA and ONR, and by the Oren Family Chair of Experimental Solid State Physics.

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